Low-power dual 2-input NAND Schmitt trigger Rev. 8 — 3 July 2017

Product data sheet

General description 1

The 74AUP2G132 provides the dual 2-input NAND Schmitt trigger function which accepts standard input signals. They can transform slowly changing input signals into sharply defined, jitter-free output signals.

This device ensures a very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing a damaging backflow current through the device when it is powered down.

The inputs switch at different points for positive and negative-going signals. The difference between the positive voltage V_{T+} and the negative voltage V_{T-} is defined as the input hysteresis voltage V_H.

Features and benefits 2

- Wide supply voltage range from 0.8 V to 3.6 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 5 000 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM JESD22-C101E exceeds 1 000 V
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- · Latch-up performance exceeds 100 mA per JESD 78 Class II
- Inputs accept voltages up to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- I_{OFF} circuitry provides partial Power-down mode operation
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C

Applications 3

- · Wave and pulse shaper
- Astable multivibrator
- Monostable multivibrator

ne<mark>x</mark>peria

Low-power dual 2-input NAND Schmitt trigger

4 Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP2G132DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AUP2G132GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 x 1.95 x 0.5 mm	SOT833-1
74AUP2G132GF	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1 x 0.5 mm	SOT1089
74AUP2G132GM	-40 °C to +125 °C	XQFN8	plastic, extremely thin quad flat package; no leads; 8 terminals; body 1.6 x 1.6 x 0.5 mm	SOT902-2
74AUP2G132GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 x 1.0 x 0.35 mm	SOT1116
74AUP2G132GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 x 1.0 x 0.35 mm	SOT1203
74AUP2G132GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 x 0.8 x 0.35 mm	SOT1233

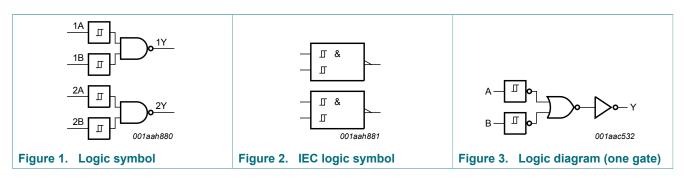
5 Marking

Table 2. Marking codes					
Type number	Marking code ^[1]				
74AUP2G132DC	aE2				
74AUP2G132GT	aE2				
74AUP2G132GF	aE				
74AUP2G132GM	aE2				
74AUP2G132GN	aE				
74AUP2G132GS	aE				
74AUP2G132GX	aE				

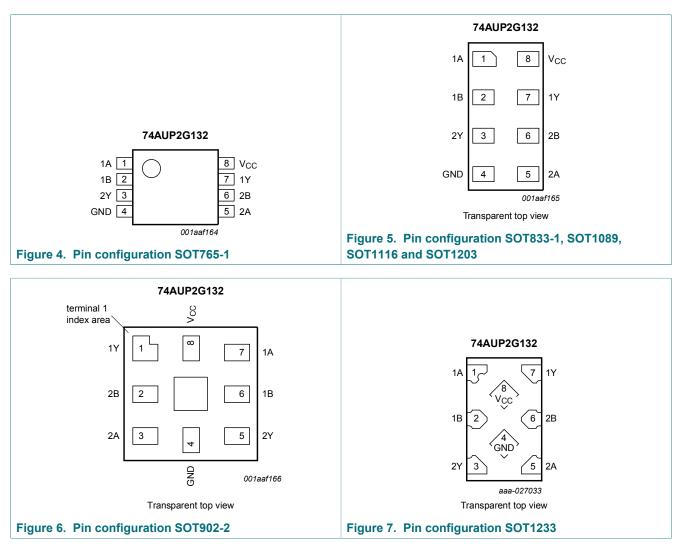
[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

Low-power dual 2-input NAND Schmitt trigger

6 Functional diagram



7 Pinning information



7.1 Pinning

74AUP2G132 Product data sheet All information provided in this document is subject to legal disclaimers. Rev. 8 — 3 July 2017

Low-power dual 2-input NAND Schmitt trigger

7.2 Pin description

Symbol	Pin	Pin			
	SOT765-1, SOT833-1, SOT1089, SOT1116, SOT1203 and SOT1233	SOT902-2			
1A, 2A	1, 5	7, 3	data input		
1B, 2B	2, 6	6, 2	data input		
GND	4	4	ground (0 V)		
1Y, 2Y	7, 3	1, 5	data output		
V _{CC}	8	8	supply voltage		

8 Functional description

Table 4. Function table

H = HIGH voltage level; L = LOW voltage level.

Input		Output
nA	nB	nY
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

4 / 25

Low-power dual 2-input NAND Schmitt trigger

Limiting values 9

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Мах	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V ₁ < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
I _{ОК}	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
I _O	output current	$V_{O} = 0 V \text{ to } V_{CC}$		-	±20	mA
I _{CC}	supply current			-	50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[2]	-	250	mW

The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed. For VSSOP8 packages: above 110 $^{\circ}$ C the value of P_{tot} derates linearly with 8.0 mW/K. [1]

[2] For XSON8 and XQFN8 packages: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

For X2SON8 package: above 118 °C the value of Ptot derates linearly with 7.7 mW/K.

10 Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V_{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C

Low-power dual 2-input NAND Schmitt trigger

11 Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = 25	°C			,	1	
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		$I_{\rm O}$ = -20 $\mu\text{A};V_{\rm CC}$ = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I	input leakage current	V_I = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
I _{OFF}	power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.2	μA
Δl _{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.2	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.5	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}^{[1]}$	-	-	40	μA
CI	input capacitance	V_{I} = GND or V_{CC} ; V_{CC} = 0 V to 3.6 V	-	1.1	-	pF
Co	output capacitance	$V_{O} = GND; V_{CC} = 0 V$	_	1.7	_	pF

Nexperia

74AUP2G132

Low-power dual 2-input NAND Schmitt trigger

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -4	0 °C to +85 °C					
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}]
		I_{O} = -20 μ A; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	$0.7 \times V_{CC}$	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		$I_{\rm O}$ = 20 µA; $V_{\rm CC}$ = 0.8 V to 3.6 V	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	$0.3 \times V_{CC}$	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.35	V
		$I_{\rm O}$ = 2.3 mA; $V_{\rm CC}$ = 2.3 V	-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.45	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.33	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.45	V
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.5	μA
ΔI_{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.6	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.9	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}^{[1]}$	-	-	50	μA

Nexperia

74AUP2G132

Low-power dual 2-input NAND Schmitt trigger

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
T _{amb} = -4	0 °C to +125 °C				1	<u></u>
V _{OH}	HIGH-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = -20 µA; V_{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	$0.6 \times V_{CC}$	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_{I} = V_{T+}$ or V_{T-}				
		I_{O} = 20 µA; V_{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		$I_{\rm O}$ = 2.3 mA; $V_{\rm CC}$ = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I_{O} = 2.7 mA; V_{CC} = 3.0 V	-	-	0.36	V
		I_{O} = 4.0 mA; V_{CC} = 3.0 V	-	-	0.50	V
lı	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_1 or V_0 = 0 V to 3.6 V; V_{CC} = 0 V	-	-	±0.75	μA
ΔI_{OFF}	additional power-off leakage current	$V_1 \text{ or } V_0 = 0 \text{ V to } 3.6 \text{ V;}$ $V_{CC} = 0 \text{ V to } 0.2 \text{ V}$	-	-	±0.75	μA
I _{CC}	supply current	$V_{I} = GND \text{ or } V_{CC}; I_{O} = 0 \text{ A};$ $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	1.4	μA
ΔI _{CC}	additional supply current	$V_{I} = V_{CC} - 0.6 \text{ V}; I_{O} = 0 \text{ A}; V_{CC} = 3.3 \text{ V}^{[1]}$	-	-	75	μA

[1] One input at V_{CC} - 0.6 V, other input at V_{CC} or GND.

Low-power dual 2-input NAND Schmitt trigger

12 Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Figure 9.

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} =	-40 °C to	+125 °C	Unit
				Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 5 pF									
t _{pd}	propagation delay	nA or nB to nY; see Figure 8 ^[2]							
		V _{CC} = 0.8 V	-	22.5	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	6.3	13.4	2.4	15.1	16.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.6	8.2	1.9	9.7	10.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.9	6.6	1.7	7.9	8.7	ns
		V_{CC} = 2.3 V to 2.7 V	1.7	3.2	5.3	1.5	6.2	6.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	2.9	4.7	1.4	5.6	6.2	ns
C _L = 10 p	F				1			1	
t _{pd}	propagation delay	nA or nB to nY; see Figure 8 ^[2]							
		V _{CC} = 0.8 V	-	26.1	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.0	7.2	15.4	2.7	17.3	19.0	ns
		V _{CC} = 1.4 V to 1.6 V	2.5	5.2	9.3	2.2	11.0	12.1	ns
		V _{CC} = 1.65 V to 1.95 V	2.3	4.5	7.5	2.0	9.0	9.9	ns
		V_{CC} = 2.3 V to 2.7 V	2.1	3.8	6.1	1.8	7.2	7.9	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	5.5	1.8	6.5	7.2	ns
C _L = 15 p	F							1	
t _{pd}	propagation delay	nA or nB to nY; see Figure 8 ^[2]							
		V _{CC} = 0.8 V	-	29.6	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.3	8.0	17.2	3.0	19.4	21.3	ns
		V _{CC} = 1.4 V to 1.6 V	2.8	5.8	10.4	2.5	12.3	13.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	5.0	8.3	2.3	10.0	11.0	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	4.2	6.7	2.1	7.9	8.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	3.9	6.1	2.0	7.3	8.0	ns

Nexperia

Low-power dual 2-input NAND Schmitt trigger

Symbol	Parameter	Conditions	T _{amb} = 25 °C			T _{amb} = -40 °C to +125 °C			Unit
			Min	Typ ^[1]	Max	Min	Max (85 °C)	Max (125 °C)	
C _L = 30 p	F			1					
t _{pd}	propagation delay	nA or nB to nY; see Figure 8 ^[2]							
		V _{CC} = 0.8 V	-	39.9	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	10.2	22.6	3.8	25.4	27.9	ns
		V _{CC} = 1.4 V to 1.6 V	3.6	7.3	13.3	3.2	15.8	17.4	ns
		V _{CC} = 1.65 V to 1.95 V	3.2	6.3	10.6	2.9	12.8	14.1	ns
		V _{CC} = 2.3 V to 2.7 V	3.0	5.3	8.5	2.7	10.1	11.1	ns
		V _{CC} = 3.0 V to 3.6 V	2.8	5.0	7.8	2.7	9.2	10.1	ns
C _L = 5 pF	, 10 pF, 15 pF and 3	0 pF		1		1			
C _{PD}	power dissipation	f_i = 1 MHz; V_I = GND to V_{CC} ^[3]							
	capacitance	V _{CC} = 0.8 V	-	2.6	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.9	-	-	-	-	pF
		V _{CC} = 1.4 V to 1.6 V	-	3.0	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.2	-	-	-	-	pF
		V_{CC} = 2.3 V to 2.7 V	-	3.8	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.4	-	-	-	-	pF

[1] [2] [3]

All typical values are measured at nominal V_{CC}. t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in µW). $P_D = C_{PD} \times V_{CC}^2 \propto f_i \times N + \Sigma(C_L \times V_{CC}^2 \propto f_0)$ where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

 C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

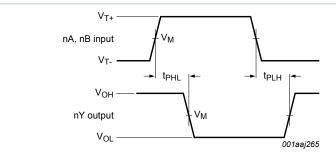
N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_0)$ = sum of the outputs.

10 / 25

Low-power dual 2-input NAND Schmitt trigger

12.1 Waveforms and test circuit



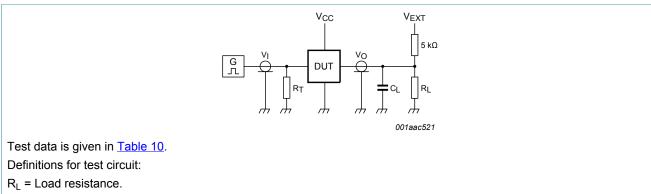
Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 8. The data input (nA or nB) to output (nY) propagation delays

Table 9. Measuremer	nt points
---------------------	-----------

Supply voltage	Output	Input		
V _{cc}	V _M	V _M	VI	$t_r = t_f$
0.8 V to 3.6 V	0.5 x V _{CC}	0.5 x V _{CC}	V _{CC}	≤ 3.0 ns



 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to the output impedance Z_0 of the pulse generator.

 V_{EXT} = External voltage for measuring switching times.

Figure 9. Test circuit for measuring switching times

Table 10. Test data

Supply voltage	Load	V _{EXT}			
V _{cc}	CL	R _L ^[1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 k Ω or 1 M Ω	open	GND	2 x V _{CC}

[1] $R_L = 5 k\Omega$ when measuring enable and disable times. $R_L = 1 M\Omega$ when measuring propagation delays, setup and hold times and pulse width.

Low-power dual 2-input NAND Schmitt trigger

13 Transfer characteristics

Table 11. Transfer characteristics

Voltages are referenced to GND (ground = 0 V; for test circuit see Figure 9.

Symbol	Parameter	Conditions	Tai	$T_{amb} = 25 \text{ °C}$ $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$		+125 °C	Contraction Contractica Contra		
			Min	Тур	Мах	Min	Max (85 °C)	Max (125 °C)	
	positive-going threshold voltage	see <u>Figure 10</u> and <u>Figure 11</u>							
		V _{CC} = 0.8 V	0.30	-	0.60	0.30	0.60	0.62	V
		V _{CC} = 1.1 V	0.53	-	0.90	0.53	0.90	0.92	V
		V _{CC} = 1.4 V	0.74	-	1.11	0.74	1.11	1.13	V
		V _{CC} = 1.65 V	0.91	-	1.29	0.91	1.29	1.31	V
		V _{CC} = 2.3 V	1.37	-	1.77	1.37	1.77	1.80	V
		V _{CC} = 3.0 V	1.88	-	2.29	1.88	2.29	2.32	V
V _{T-}	negative-going threshold voltage	see <u>Figure 10</u> and <u>Figure 11</u>							
		V _{CC} = 0.8 V	0.10	-	0.60	0.10	0.60	0.60	V
		V _{CC} = 1.1 V	0.26	-	0.65	0.26	0.65	0.65	V
		V _{CC} = 1.4 V	0.39	-	0.75	0.39	0.75	0.75	V
		V _{CC} = 1.65 V	0.47	-	0.84	0.47	0.84	0.84	V
		V _{CC} = 2.3 V	0.69	-	1.04	0.69	1.04	1.04	V
		V _{CC} = 3.0 V	0.88	-	1.24	0.88	1.24	1.24	V
V _H	hysteresis voltage	$(V_{T+} - V_{T-})$; see Figure 10, Figure 11, Figure 12 and Figure 13							
		V _{CC} = 0.8 V	0.07	-	0.50	0.07	0.50	0.50	V
		V _{CC} = 1.1 V	0.08	-	0.46	0.08	0.46	0.46	V
		V _{CC} = 1.4 V	0.18	-	0.56	0.18	0.56	0.56	V
		V _{CC} = 1.65 V	0.27	-	0.66	0.27	0.66	0.66	V
		V _{CC} = 2.3 V	0.53	-	0.92	0.53	0.92	0.92	V
		V _{CC} = 3.0 V	0.79	-	1.31	0.79	1.31	1.31	V

160

80

0

0

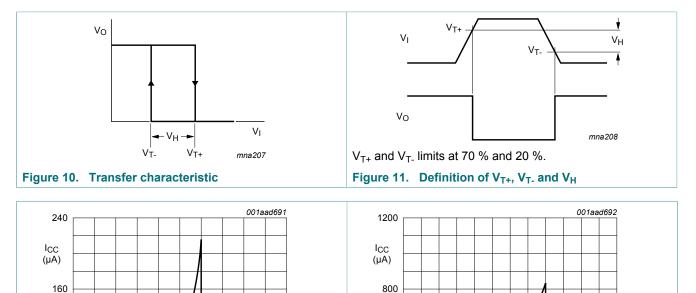
0.4

0.8

1.2

74AUP2G132

Low-power dual 2-input NAND Schmitt trigger



13.1 Waveforms transfer characteristics



1.6 _{VI (V)} 2.0

400

0

0

1.0

2.0

 $V_{I}(V)$

3.0

Low-power dual 2-input NAND Schmitt trigger

14 Application information

The slow input rise and fall times cause additional power dissipation which can be calculated using the following formula:

 $P_{add} = f_i x (t_r \times \Delta I_{CC(AV)} + t_f x \Delta I_{CC(AV)}) x V_{CC}$ where:

- P_{add} = additional power dissipation (μW);
- f_i = input frequency (MHz);
- t_r = input rise time (ns); 10 % to 90 %;
- t_f = input fall time (ns); 90 % to 10 %;
- $\Delta I_{CC(AV)}$ = average additional supply current (µA).

Average $\Delta I_{CC(AV)}$ differs with positive or negative input transitions, as shown in Figure 14.

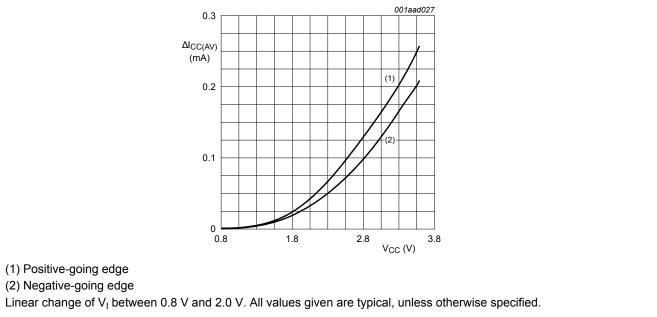


Figure 14. Average I_{CC} as a function of V_{CC}

14 / 25

Low-power dual 2-input NAND Schmitt trigger

15 Package outline

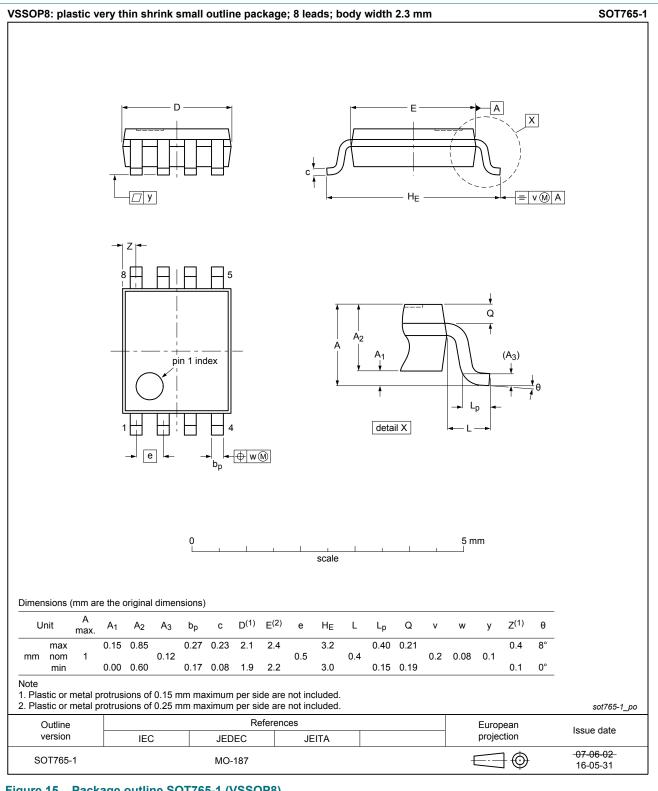


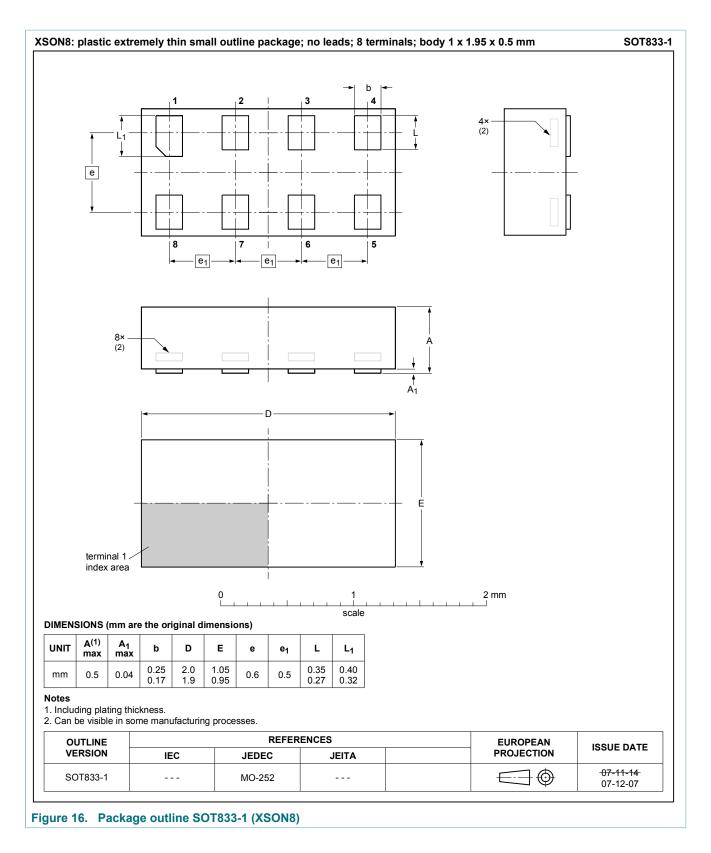
 Figure 15.
 Package outline SOT765-1 (VSSOP8)

All information provided in this document is subject to legal disclaimers.

Product data sheet

74AUP2G132

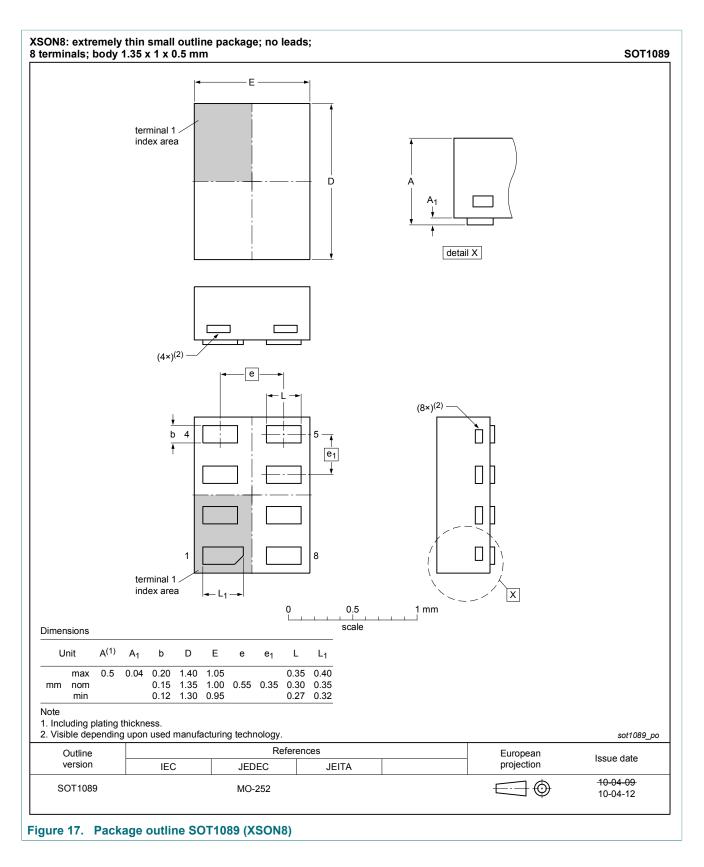
Low-power dual 2-input NAND Schmitt trigger



Nexperia

74AUP2G132

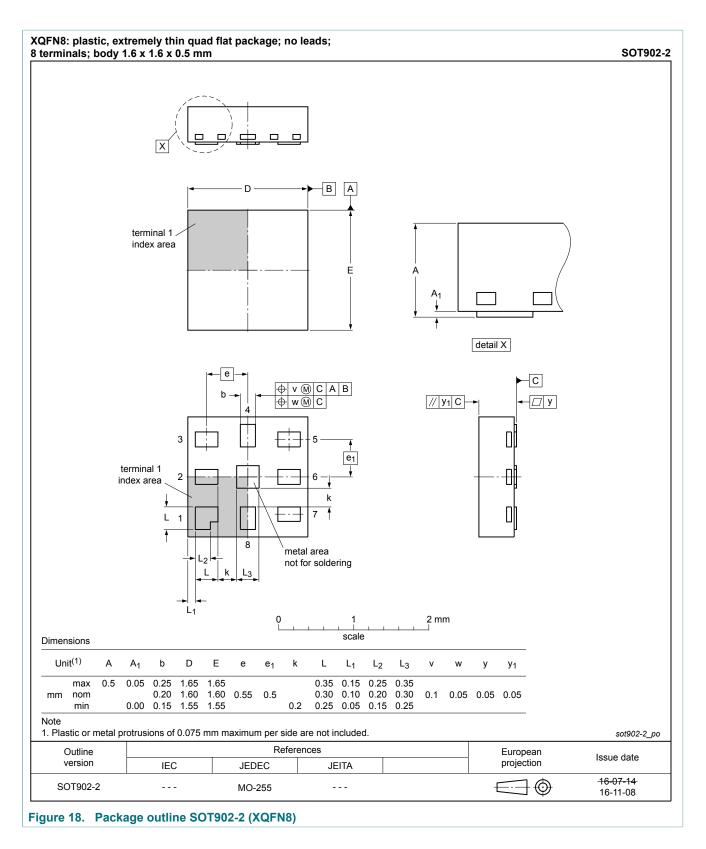
Low-power dual 2-input NAND Schmitt trigger



74AUP2G132 Product data sheet

All information provided in this document is subject to legal disclaimers. Rev. 8 — 3 July 2017 © Nexperia B.V. 2017. All rights reserved.

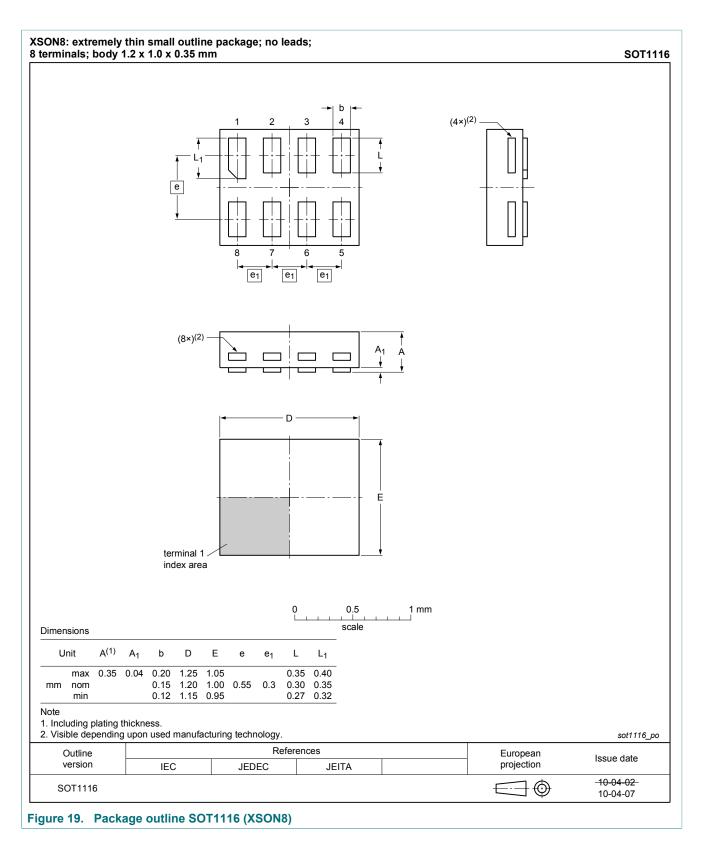
Low-power dual 2-input NAND Schmitt trigger



74AUP2G132 Product data sheet

All information provided in this document is subject to legal disclaimers.

Low-power dual 2-input NAND Schmitt trigger

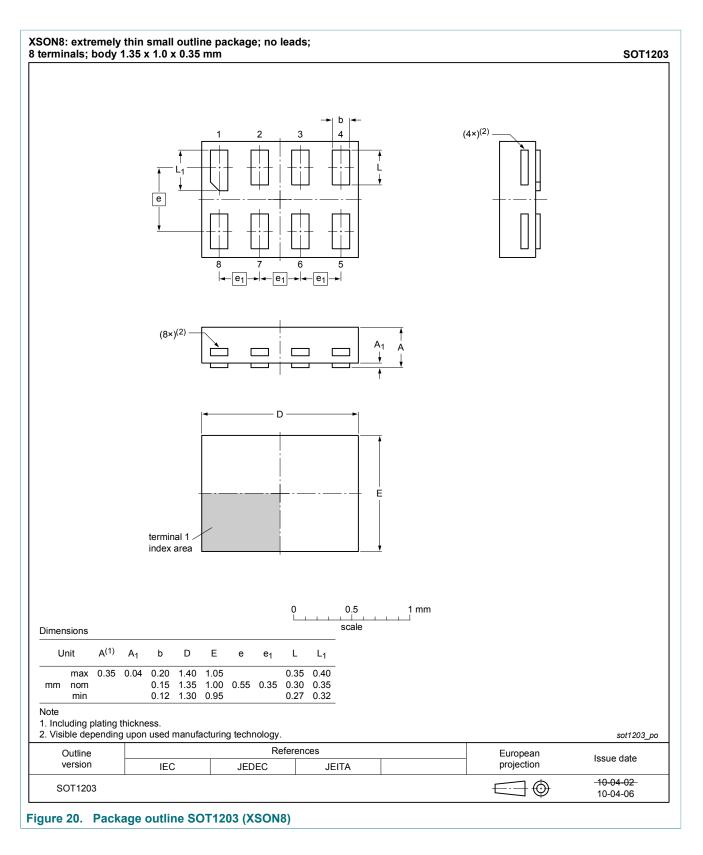


74AUP2G132 Product data sheet

All information provided in this document is subject to legal disclaimers.

Rev. 8 — 3 July 2017

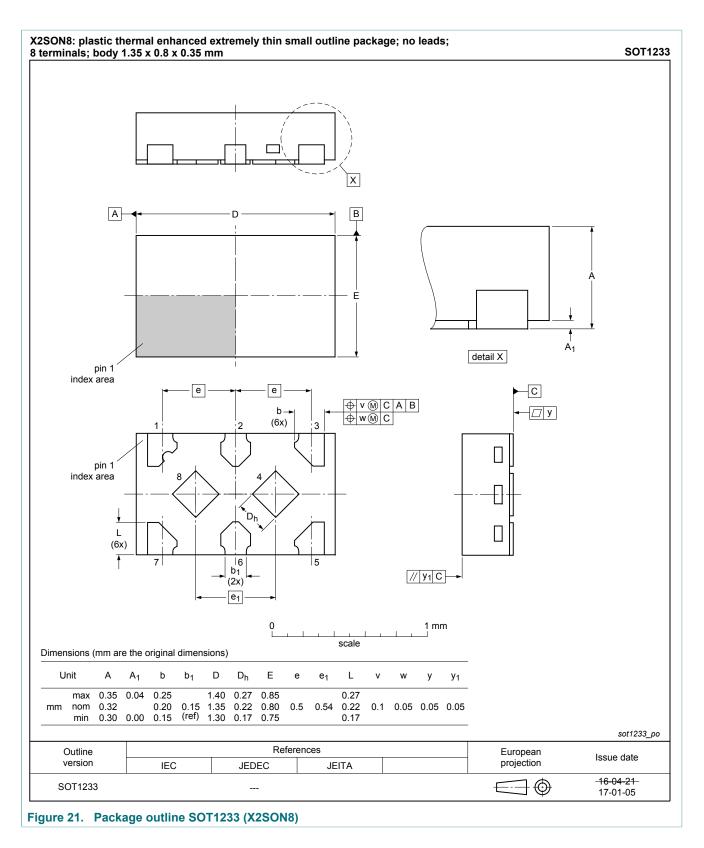
Low-power dual 2-input NAND Schmitt trigger



74AUP2G132 Product data sheet

All information provided in this document is subject to legal disclaimers.

Low-power dual 2-input NAND Schmitt trigger



74AUP2G132 Product data sheet All information provided in this document is subject to legal disclaimers.

Rev. 8 — 3 July 2017

Low-power dual 2-input NAND Schmitt trigger

16 Abbreviations

Table 12. Abbreviations				
Acronym	Description			
CDM	Charged Device Model			
DUT	Device Under Test			
ESD	ElectroStatic Discharge			
HBM	Human Body Model			
MM	Machine Model			

17 Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AUP2G132 v.8	20170703	Product data sheet	-	74AUP2G132 v.7			
Modifications:	Nexperia. Legal texts have Type number 7 	his data sheet has been redesi ve been adapted to the new co 74AUP2G132GX (SOT1233 / X 74AUP2G132GD removed.	mpany name where				
74AUP2G132 v.7	20130208	Product data sheet	-	74AUP2G132 v.6			
Modifications:	 For type numb 	For type number 74AUP2G132GD XSON8U has changed to XSON8.					
74AUP2G132 v.6	20120803	Product data sheet	-	74AUP2G132 v.5			
74AUP2G132 v.5	20111201	Product data sheet	-	74AUP2G132 v.4			
74AUP2G132 v.4	20101104	Product data sheet	-	74AUP2G132 v.3			
74AUP2G132 v.3	20081215	Product data sheet	-	74AUP2G132 v.2			
74AUP2G132 v.2	20080314	Product data sheet	-	74AUP2G132 v.1			
74AUP2G132 v.1	20061018	Product data sheet	-	-			

Low-power dual 2-input NAND Schmitt trigger

18 Legal information

18.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

Please consult the most recently issued document before initiating or completing a design. [1]

The term 'short data sheet' is explained in section "Definitions".

[2] [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nexperia.com.

18.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. Nexperia does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local Nexperia sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

Product specification - The information and data provided in a Product data sheet shall define the specification of the product as agreed between Nexperia and its customer, unless Nexperia and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the Nexperia product is deemed to offer functions and qualities beyond those described in the Product data sheet.

18.3 Disclaimers

Limited warranty and liability - Information in this document is believed to be accurate and reliable. However, Nexperia does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. Nexperia takes no responsibility for the content in this document if provided by an information source outside of Nexperia. In no event shall Nexperia be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory. Notwithstanding any damages that customer might incur for any reason whatsoever, Nexperia's aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the Terms and conditions of commercial sale of Nexperia

Right to make changes - Nexperia reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use - Nexperia products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an Nexperia product can reasonably be expected to result in personal injury, death or severe property or environmental damage. Nexperia and its suppliers accept no liability for inclusion and/or use of Nexperia products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. Nexperia makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification. Customers are responsible for the design and operation of their applications and products using Nexperia products, and Nexperia accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the Nexperia product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products. Nexperia does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using Nexperia products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). Nexperia does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale - Nexperia products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nexperia.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. Nexperia hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of Nexperia products by customer

No offer to sell or license - Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

74AUP2G132 **Product data sheet** All information provided in this document is subject to legal disclaimers. Rev. 8 - 3 July 2017

23 / 25

Low-power dual 2-input NAND Schmitt trigger

Non-automotive qualified products — Unless this data sheet expressly states that this specific Nexperia product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. Nexperia accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications. In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without Nexperia's warranty of the product for such automotive applications, use and specifications beyond Nexperia's specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies Nexperia for any liability, damages or failed product claims resulting from customer

design and use of the product for automotive applications beyond Nexperia's

Translations — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy

18.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

standard warranty and Nexperia's product specifications.

between the translated and English versions.

Nexperia

74AUP2G132

Low-power dual 2-input NAND Schmitt trigger

Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Ordering information	2
5	Marking	
6	Functional diagram	3
7	Pinning information	
7.1	Pinning	
7.2	Pin description	
8	Functional description	
9	Limiting values	
10	Recommended operating conditions	5
11	Static characteristics	
12	Dynamic characteristics	9
12.1	Waveforms and test circuit	11
13	Transfer characteristics	12
13.1	Waveforms transfer characteristics	
14	Application information	14
15	Package outline	
16	Abbreviations	
17	Revision history	
18	Legal information	

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© Nexperia B.V. 2017.

All rights reserved.

For more information, please visit: http://www.nexperia.com For sales office addresses, please send an email to: salesaddresses@nexperia.com

Date of release: 3 July 2017 Document identifier: 74AUP2G132



单击下面可查看定价,库存,交付和生命周期等信息

>>Nexperia(安世)